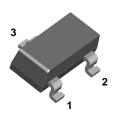
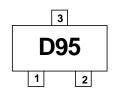


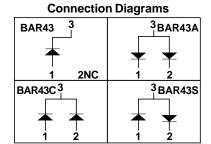
BAR43/A/C/S



SOT-23



MARKING
BAR43 D95 BAR43A DB1
BAR43C DB2 BAR43S DA5



Schottky Diodes

$\begin{tabular}{lll} \textbf{Absolute Maximum Ratings*} & $T_A = 25^{\circ}$C unless otherwise noted \end{tabular}$

Symbol	Parameter	Value	Units
V_{RRM}	Maximum Repetitive Reverse Voltage	30	V
I _{F(AV)}	Average Rectified Forward Current	200	mA
I _{FSM}	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 second	750	mA
T _{stg}	Storage Temperature Range	-55 to +150	°C
T _J	Operating Junction Temperature	150	°C

 $^{{}^{\}textstyle \star} \text{These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.}$

Thermal Characteristics

Symbol	Parameter	Value	Units
P_{D}	Power Dissipation	290	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient		°C/W

Electrical Characteristics T_A = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
V_R	Breakdown Voltage	$I_R = 100 \mu A$	30		V
V _F	Forward Voltage	$I_F = 2.0 \text{ mA}$ $I_F = 15 \text{ mA}$ $I_F = 100 \text{ mA}$	260	330 450 1.0	mV mV V
I _R	Reverse Current	V _R = 25 V V _R = 25 V, T _A = 100°C		0.5 100	μΑ μΑ
t _{rr}	Reverse Recovery Time	$I_F = I_R = 10 \text{ mA}, I_{RR} = 1.0 \text{ mA},$ $R_L = 100 \Omega$		5.0	ns
	Minimum Detection Recovery Time $I_F = I_R = 10$ mA, $I_{RR} = 1.0$ mA, $I_{RR} = 1.0$ mA, $I_{RR} = 1.0$ mA,			80%	

^{**}Mounted on ceramic substrate 10mm x 8mm x 0.6mm.

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PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
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